

Tantalum, MnO2 Tantalum, High Temperature, T499, 10 uF, 10%, 35 V, 7343, SMD, MnO2, Molded, Hi-Temp, 175C, Auto, AEC-Q200, N/A, 1 Ohms, Height Max = 3.1mm



General Information	
<b>Dielectric:</b>	MnO2 Tantalum
<b>Style:</b>	SMD Chip
<b>Series:</b>	T499
<b>Description:</b>	SMD, MnO2, Molded, Hi-Temp, 175C, Auto, AEC-Q200
<b>Features:</b>	Automotive, 175C
<b>RoHS:</b>	Yes
<b>Termination:</b>	Tin
<b>Approvals:</b>	AEC-Q200
<b>AEC-Q200:</b>	Yes

Dimensions	
<b>Footprint</b>	7343
<b>L</b>	7.3mm +/-0.3mm
<b>W</b>	4.3mm +/-0.3mm
<b>H</b>	2.8mm +/-0.3mm
<b>T</b>	0.13mm REF
<b>S</b>	1.3mm +/-0.3mm
<b>F</b>	2.4mm +/-0.1mm
<b>A</b>	3.8mm MIN
<b>B</b>	0.5mm +/-0.15mm
<b>E</b>	3.5mm REF
<b>G</b>	3.5mm REF
<b>P</b>	0.9mm REF
<b>R</b>	1mm REF
<b>X</b>	0.1mm +/-0.1mm

Specifications	
<b>Capacitance:</b>	10 uF
<b>Capacitance Tolerance:</b>	10%
<b>Voltage DC:</b>	35 VDC (85C), 27.22 VDC (125C), 11.7 VDC (175C)
<b>Temperature Range:</b>	-55/+175C
<b>Dissipation Factor:</b>	6% 120Hz 20C
<b>Failure Rate:</b>	N/A
<b>Resistance:</b>	1000 mOhms (100kHz)
<b>Current:</b>	387 mAmps (100kHz 25C), 348.3 mAmps (85C), 77.4 mAmps (175C)
<b>Leakage Current:</b>	3.5 uAmps (5min 20C)

Packaging Specifications	
<b>Weight:</b>	446.84 mg
<b>Packaging:</b>	T&R, 178mm
<b>Packaging Quantity:</b>	500

Statements of suitability for certain applications are based on our knowledge of typical operating conditions for such applications, but are not intended to constitute - and we specifically disclaim - any warranty concerning suitability for a specific customer application or use. This Information is intended for use only by customers who have the requisite experience and capability to determine the correct products for their application. Any technical advice inferred from this Information or otherwise provided by us with reference to the use of our products is given gratis, and we assume no obligation or liability for the advice given or results obtained.